# Quantum computation with three-electron double quantum dots at an optimal operation point

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The author analyzes quantum computation with the hybrid qubit (HQ) that is encoded using the three-electron configuration of a double quantum dot. All gate operations are controlled with electric signals, while the qubit remains at an optimal operation point that is insensitive to noise. An effective single-qubit description is derived, and two-qubit interactions are suggested using Coulomb and exchange interactions. Universal quantum control is described and numerically simulated using realistic parameters for HQs in Si and GaAs. High-fidelity quantum computing at the threshold of quantum error correction is possible if the Coulomb interactions between the HQs stay weak.

### I. INTRODUCTION

Spin qubit quantum computers are promising platforms to achieve quantum computation. <sup>1,2</sup> The electron spin of a gate-defined quantum dot (QD) naturally defines a two-level quantum system that encodes one bit of quantum information. <sup>1,3</sup> Also a duo, <sup>4,5</sup> a trio, <sup>6</sup> and a quartet <sup>7,8</sup> of such singly occupied QDs have been proposed as realizations of quantum bits. The so-called hybrid qubit (HQ) is encoded using a double QD (DQD) that is occupied with three electrons. <sup>9</sup> The name HQ was introduced because the HQ is either a spin or a charge qubit depending on its operation principle. A spin qubit is well protected from charge noise, but typical spin qubits cannot be operated all-electrically. A charge qubit can be manipulated with electric fields, but it is therefore also susceptible to charge noise.

The HQ can be operated exclusively with electric signals similar to the triple QD (TQD) qubit that is coded using three singly occupied QDs.  $^{6,9}$  Because subnanosecond controls of the electrostatic potentials of QDs can be realized,  $^{10,11}$  electric manipulations of QD qubits are always more favorable than magnetic manipulations. Even though single spins can also be controlled with magnetic field pulses,  $^{12,13}$  it is difficult to selectively control a single spin with magnetic fields when this spin is in the vicinity of other spins.  $^{14}$  Electric fields can also modify single spins indirectly (e.g. via spin-orbit interactions or magnetic field gradients), but high-fidelity gates still remain challenging.  $^{15-17}$ 

Most conveniently, the HQ is manipulated by the transfer between the  $(n_{\rm QD_1}, n_{\rm QD_2}) = (1,2)$  and (2,1) configurations,  $^{9,18-21}$  similar to a charge qubit.  $^{22-24}$   $n_{\rm QD_1}$  and  $n_{\rm QD_2}$  are the electron numbers at QD<sub>1</sub> and QD<sub>2</sub>. These manipulations require precise, subnanosecond pulses of electric signals with large amplitudes. Considerable advances for the HQ were possible using an asymmetric DQD configuration.  $^{19-21}$  For a doubly occupied QD, the addition of the second electron usually requires higher energy in the triple configuration compared to the singlet configuration. DQDs were constructed, where this singlet-triplet energy difference is small for one of the

QDs, but it is much larger for the other one.

This paper studies DQDs with asymmetric addition energies in the layout of Fig. 1.  $\rm QD_2$  always has a small singlet-triplet energy difference, but the singlet-triplet energy difference difference is large for  $\rm QD_1$ . It will be shown that the HQ has a small energy difference in the (1,2) configuration. When approaching the (2,1) configuration, the qubit states pass through two avoided level crossings. It has been described theoretically and shown experimentally  $^{19,20}$  that these two anticrossings are sufficient for the single-qubit control of the HQ with the appropriate tuning protocols through the anticrossings.

It is also possible to operate the HQ in the vicinity of an anticrossing, where all the qubit operations are realized with microwave pulses of small amplitudes. ^21 An anticrossing is a sweet spot in the energy diagram where low-frequency noise in the control parameter does not dephase the qubit. Such sweet-spot operations have improved the coherence times for superconducting qubits. ^25-27 Note that microwave gates have also been realized for other spin qubit encodings, as for DQDs ^28 and TQDs. ^29,30

For HQs, the entangling operations remain more challenging than the single-qubit gates. Ref. [9] proposed that strong electrostatic couplings can be used to entangle two HQs. Also the rapid transfer of electrons between the HQs has been studied.<sup>31</sup> In this paper, I show that the HQ can always be operated at its sweet spot while weak couplings between HQs enable two-qubit gates. I quantify the inter-qubit couplings with Coulomb and exchange interactions, and show that both interactions enable two-qubit gates.

The main findings of this paper are explicit manipulation protocols for HQs of high fidelities, while all the HQs are operated at their sweet spots. I simulate the gate operations with typical qubit parameters and show that these gates tolerate the dominant noise sources of HQs. At the sweet spot, the HQ keeps enough character of a spin qubit to be protected from charge noise, but it is already sufficiently close to a charge qubit to be rapidly tunable. To employ these gates experimentally, one has to build setups that have weak Coulomb interactions be-

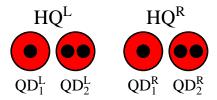


Figure 1. Setup of two HQs. Each HQ is coded using the three electron configuration of a DQD. The superscripts L and R label the positions of the HQs; the subscripts 1 and 2 label the QDs.

tween the HQs at their sweet spots.

The organization of the paper is as follows. Sec. II introduces the description of the HQ, and it specifies the magnitudes of the relevant parameters. The single-qubit control, the readout, and the initialization are also described. Sec. III derives the effective Hamiltonians for the couplings between HQs that are generated from Coulomb and exchange interactions. Sec. IV specifies two approaches to realize universal control of the HQ. Not only entangling operations are discussed, but it is also shown that single-qubit gates are possible. Sec. V discusses the influence of electric and magnetic noise for HQs that are operated at their sweet spots. Sec. VI summarizes the findings.

### II. SINGLE-QUBIT DESCRIPTION

The HQ is coded using a DQD that is occupied with three electrons, as shown in Fig. 1. The qubit manipulations require a much larger singlet-triplet energy splitting of a doubly occupied QD for QD<sub>1</sub> compared to QD<sub>2</sub>. I consider only the subspace encoding in the S=1/2,  $s_z=1/2$  spin configuration.<sup>6,32</sup> Even though a global magnetic field is not required to realize single-qubit gates, it will be necessary to apply magnetic fields to initialize a HQ to S=1/2,  $s_z=1/2$ .<sup>33</sup> QD<sub>1</sub> can be used for the initialization of a singlet because a two-electron configuration quickly equilibrates to a singlet under thermal relaxation. In the presence of an external magnetic field, also the spin-up configuration at QD<sub>2</sub> can be initialized because it has lower energy than the spin-down configuration.<sup>34</sup>

The HQ is described in the basis of the lowest states with  $S=1/2,\ s_z=1/2$ . One considers  $|\mathbf{x}\rangle=|\mathbf{S}\uparrow\rangle$  in the (2,1) configuration, and the states  $|1\rangle\propto\sqrt{2}|\downarrow \mathbf{T}_+\rangle-|\uparrow \mathbf{T}_0\rangle$  and  $|0\rangle=|\uparrow \mathbf{S}\rangle$  in the (1,2) configuration. The singlet  $|\mathbf{S}\rangle\propto|\uparrow\downarrow\rangle-|\downarrow\uparrow\rangle$  and the triplets  $|\mathbf{T}_+\rangle=|\uparrow\uparrow\rangle$ ,  $|\mathbf{T}_0\rangle\propto|\uparrow\downarrow\rangle+|\downarrow\uparrow\rangle$ , and  $|\mathbf{T}_-\rangle=|\downarrow\downarrow\rangle$  describe the two-electron configurations at a QD. The three-electron states with  $S=1/2,\ s_z=1/2$  are defined using the standard spin addition rules.<sup>35</sup> The Hamiltonian for the HQ in the

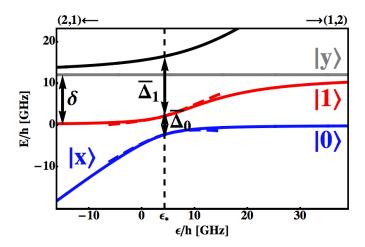


Figure 2. Energy diagram of the relevant states to describe the HQ in the S = 1/2,  $s_z = 1/2$  spin configuration of a threeelectron DQD, according to Eq. (1), for  $2\Delta_1/h = 14.5$  GHz,  $2\Delta_0/h = 5.2$  GHz, and  $\delta/h = 12.1$  GHz.  $\epsilon$  models the energy detuning between the (2,1) and (1,2) charge configurations. The HQ is coded using the two states with the lowest energies. The HQ is in (1,2) for  $\epsilon \to \infty$  with the excited state  $|1\rangle \propto$  $\sqrt{2} |\downarrow T_{+}\rangle - |\uparrow T_{0}\rangle$  and the ground state  $|0\rangle = |\uparrow S\rangle$ . Only the ground state  $|x\rangle = |S\uparrow\rangle$  is in (2,1) for  $\epsilon \to -\infty$ , while the excited state remains in (1, 2). There are two state couplings  $(|1\rangle \leftrightarrow |x\rangle \text{ and } |0\rangle \leftrightarrow |x\rangle)$  at  $\epsilon \sim 0$ . The gray line shows the S = 3/2,  $s_z = 1/2$  state (called  $|y\rangle$ ) in (1,2) that is uncoupled to (2,1). All gate operations for the HQ are realized at the sweet spot  $\epsilon_*$ , where the qubit is insensitive to small variations in  $\epsilon$ . The dashed lines approximate the qubit levels in the vicinity of  $\epsilon_*$  [see Eq. (3)]. The parameters  $\overline{\Delta}_1$  and  $\overline{\Delta}_0$  are defined in the text.

basis  $\{|x\rangle, |1\rangle, |0\rangle\}$  is

$$\mathcal{H}_{\{|\mathbf{x}\rangle,|\mathbf{1}\rangle,|\mathbf{0}\rangle\}} = \begin{pmatrix} \epsilon & -\Delta_1 & \Delta_0 \\ -\Delta_1 & \delta & 0 \\ \Delta_0 & 0 & 0 \end{pmatrix}. \tag{1}$$

The Coulomb repulsion is high for a doubly occupied QD in the triplet configuration, which raises the energy of  $|1\rangle$  compared to  $|0\rangle$  by  $\delta.$   $|\mathbf{x}\rangle$  and  $|1\rangle$  ( $|\mathbf{x}\rangle$  and  $|0\rangle$ ) are coupled via the real parameter  $\Delta_1>0$  ( $\Delta_0>0$ ), which is called the tunnel coupling in the following.  $\epsilon$  is the detuning parameter between the (2,1) and (1,2) configurations. The electron configuration in (2,1) [(1,2)] has lower energy for  $\epsilon<0$  [ $\epsilon>0$ ], and (2,1) and (1,2) have equal energies at  $\epsilon=0$ .

Eq. (1) describes a three level system with two anti-crossings. Fig. 2 shows the energy levels for typical qubit parameters in the transition region between (2,1) and (1,2). The two states with the lowest energies encode the HQ. For  $\epsilon \ll 0$ , only the ground state is in (2,1), while the first excited state is in (1,2). This configuration is ideal for the readout of the HQ because a nearby charge detector can distinguish the two states of the HQ, similar to the readout of a singlet-triplet qubit.  $^{36-38}$  For  $\epsilon \gg 0$ , the HQ is in (1,2) and the energy difference between the qubit states is unchanged when  $\epsilon$  is slightly

modified. This regime is highly protected from charge noise.<sup>39,40</sup> Note that there is additionally one S=3/2,  $s_z=1/2$  state in the (1,2) configuration (called  $|y\rangle$ ) that is uncoupled to the (2,1) configuration.

I consider a HQ with similar magnitudes of the singlettriplet energy splitting at QD<sub>2</sub>  $\delta$  and the tunnel couplings  $\Delta_1$  and  $\Delta_0$ :  $\delta \gtrsim \Delta_1, \Delta_0$ . The singlet-triplet energy splitting at QD<sub>1</sub> is much larger than  $\delta$  such that doubly occupied triplets at QD<sub>1</sub> are neglected. Note that such HQs have been realized using Si DQDs, <sup>19–21</sup> where the singlet-triplet energy difference depends on the orbital and the valley energy splittings. The orbital energy splitting is determined by the confining potential of a QD, while the valley energy splitting is determined by the potential landscape at the atomic scale. A recent experiment showed that the valley splitting of a Si QD can be controlled electrically. 41 Note that HQs can also be build using GaAs QDs, but these setups necessarily require asymmetric DQD potentials to operate them with the equivalent tuning pulses. In this case, the smaller QD has a large singlet-triplet splitting; the larger or elliptic QD has a small singlet-triplet splitting. 42-44 The parameters of previous experiments with Si HQs are used in the following:  $2\Delta_1/h = 14.5$  GHz,  $2\Delta_0/h = 5.2$  GHz, and  $\delta/h = 12.1 \text{ GHz (cf. Refs. } [19,20,21]).$ 

 $\Delta_1$  in Eq. (1) is caused by the coupling to an exited orbital, which is larger than the ground state orbital that determines  $\Delta_0$ . Tunnel couplings are exponentially suppressed with the distance between localized orbitals. Therefore,  $\Delta_1$  is significantly larger than  $\Delta_0$ , and it is meaningful to analyze Eq. (1) in the eigenbasis of the larger anticrossing. The states are rotated to  $|\tilde{\mathbf{x}}\rangle = \cos(\theta_\epsilon/2) |\mathbf{x}\rangle + \sin(\theta_\epsilon/2) |1\rangle$  and  $|\tilde{1}\rangle = -\sin(\theta_\epsilon/2) |\mathbf{x}\rangle + \cos(\theta_\epsilon/2) |1\rangle$ , with  $\sin(\theta_\epsilon) = -2\Delta_1/U_\epsilon$ ,  $\cos(\theta_\epsilon) = (\epsilon - \Delta)/U_\epsilon$ , and  $U_\epsilon = \sqrt{(2\Delta_1)^2 + (\epsilon - \delta)^2}$ . This basis rotation modifies Eq. (1) to

$$\mathcal{H}_{\left\{|\widetilde{\mathbf{x}}\rangle, |\widetilde{\mathbf{1}}\rangle, |0\rangle\right\}} = \tag{2}$$

$$\begin{pmatrix} \frac{\epsilon + \delta}{2} + \frac{U_{\epsilon}}{2} & 0 & \Delta_{0} \cos\left(\frac{\theta_{\epsilon}}{2}\right) \\ 0 & \frac{\epsilon + \delta}{2} - \frac{U_{\epsilon}}{2} & -\Delta_{0} \sin\left(\frac{\theta_{\epsilon}}{2}\right) \\ \Delta_{0} \cos\left(\frac{\theta_{\epsilon}}{2}\right) & -\Delta_{0} \sin\left(\frac{\theta_{\epsilon}}{2}\right) & 0 \end{pmatrix}.$$

The coupling of  $|\widetilde{\mathbf{x}}\rangle$  to  $\{\left|\widetilde{1}\right\rangle, \left|0\right\rangle\}$  is neglected in Eq. (2) to describe the low-energy subspace that defines the HQ. It will be shown that the latter subspace has an anticrossing at  $\epsilon_* = \Delta_1^2/\delta$ , while  $U_{\epsilon_*} \gg \Delta_0$ . The two-level system  $\{\left|\widetilde{1}\right\rangle, \left|0\right\rangle\}$  is approximated by:

$$\mathcal{H}_{\left\{\left|\left.\overline{1}\right\rangle,\left|\left.\overline{0}\right\rangle\right.\right\}} \approx \frac{\overline{\Delta}_{0}}{2} \sigma_{z} + \mathcal{A}\left(\epsilon\right) \sigma_{x},\tag{3}$$

with  $\overline{\Delta}_0 = 2\Delta_0 \sin(\theta_*/2)$ ,  $\mathcal{A}(\epsilon) = \frac{\delta^2}{2(\delta^2 + \Delta_1^2)} (\epsilon - \epsilon_*)$ , and  $\theta_* = \theta_{\epsilon_*}$ . To derive Eq. (3), the dependency of  $\sin(\theta_{\epsilon}/2)$  on  $\epsilon$  is neglected because this term varies slowly in the vicinity of  $\epsilon_*$ . Then the qubit's energy

 $\begin{array}{l} \mathrm{splitting} \; \sqrt{\left(\frac{\epsilon+\delta-U_{\epsilon}}{4}\right)^2 + \left[\Delta_0\sin\left(\theta_*\right)\right]^2} \; \mathrm{within} \; \left\{\left|\widetilde{1}\right\rangle, \left|0\right\rangle\right\} \\ \mathrm{is} \; \mathrm{minimized} \; \mathrm{with} \; \mathrm{respect} \; \mathrm{to} \; \epsilon, \; \mathrm{giving} \; \mathrm{the} \; \mathrm{first} \; \mathrm{term} \\ \mathrm{in} \; \mathrm{Eq.} \; (3), \; \mathrm{with} \; \overline{\Delta}_0 \; = \; 2\Delta_0\sin\left(\theta_*/2\right) \; \mathrm{for} \; \epsilon_* \; \approx \\ \Delta_1^2/\delta. \; \; \mathrm{The} \; \mathrm{second} \; \mathrm{term} \; \mathrm{in} \; \mathrm{Eq.} \; (3) \; \mathrm{is} \; \mathrm{obtained} \; \mathrm{from} \\ \sqrt{\partial_{\epsilon} \left(\frac{\epsilon+\delta-U_{\epsilon}}{4}\right)^2 + \partial_{\epsilon} \left[\Delta_0\sin\left(\theta_*\right)\right]^2} \bigg|_{\epsilon=\epsilon_*} , \; \mathrm{giving} \; \frac{\delta^2}{2\left(\delta^2+\Delta_1^2\right)}. \end{array}$ 

The basis in Eq. (3) has been rotated to

$$\left| \overline{1} \right\rangle = \frac{1}{\sqrt{2}} \left[ -\sin\left(\frac{\theta_*}{2}\right) \left| x \right\rangle + \cos\left(\frac{\theta_*}{2}\right) \left| 1 \right\rangle + \left| 0 \right\rangle \right], \tag{4}$$

$$\left|\overline{0}\right\rangle = \frac{1}{\sqrt{2}} \left[ -\sin\left(\frac{\theta_*}{2}\right) \left| \mathbf{x} \right\rangle + \cos\left(\frac{\theta_*}{2}\right) \left| 1 \right\rangle - \left| 0 \right\rangle \right], (5)$$

with the definitions of the Pauli operators  $\sigma_z = |\overline{1}\rangle\langle\overline{1}| - |\overline{0}\rangle\langle\overline{0}|$  and  $\sigma_x = |\overline{1}\rangle\langle\overline{0}| + |\overline{0}\rangle\langle\overline{1}|$ . Note that  $|\overline{1}\rangle$  and  $|\overline{0}\rangle$  have finite contributions in (2,1) and (1,2).  $\theta_* \approx 1.34\pi$  is the mixing angle, with  $\cos^2(\theta_*/2) \approx 0.26$  and  $\sin^2(\theta_*/2) \approx 0.74$ . Fig. 2 proofs that the effective two level system in Eq. (3) describes the HQ close to  $\epsilon_*$ . The leakage state  $|\widetilde{x}\rangle$  is raised by  $\overline{\Delta}_1 = \delta + \Delta_1^2/\delta$ .  $\overline{\Delta}_0 = 2\Delta_0\sin(\theta_*/2)$  is the energy difference between  $|\overline{1}\rangle$  and  $|\overline{0}\rangle$ .

Eq. (3) permits the usual Rabi control of the qubit with microwave drives of the detuning parameter  $\epsilon$ .  $^{45,46}$  If  $\epsilon$  is driven with small amplitudes around  $\epsilon_*$  [ $\mathcal{A}(\epsilon) \to \mathcal{A}\cos(2\pi\Omega t/h + \phi)$ ], then all possible single-qubit operations can be realized for  $\Omega = \overline{\Delta}_0$  when the phase  $\phi$  is varied. Eq. (3) gives in the rotating frame with  $\frac{\overline{\Delta}_0}{2}\sigma_z$  the static Hamiltonian

$$\mathcal{H}^{\text{rwa}} = \mathcal{A} \left[ \cos \left( \phi \right) \sigma_x + \sin \left( \phi \right) \sigma_y \right]. \tag{6}$$

Eq. (6) uses implicitly a rotating wave approximation, which is valid for  $\overline{\Delta}_0 \gg \mathcal{A}$ .

### III. TWO-QUBIT INTERACTIONS

This section describes the interactions between two HQs. The superscripts L and R label the positions of the HQs.  $\mathrm{QD}_2^{\mathrm{L}}$  and  $\mathrm{QD}_1^{\mathrm{R}}$  are the neighboring QDs from  $\mathrm{HQ}^{\mathrm{L}}$  and  $\mathrm{HQ}^{\mathrm{R}}$  (cf. Fig. 1).

### A. Capacitive Coupling

The charge configurations of two HQs couple capacitively via the Coulomb interaction. The dominant contribution is determined by the electron configurations at QD\_2^L  $(n_{\mathrm{QD}_2^L})$  and QD\_1^R  $(n_{\mathrm{QD}_1^R})$  according to

$$C = \kappa \ n_{\text{QD}_2^{\text{L}}} n_{\text{QD}_1^{\text{R}}}. \tag{7}$$

The magnitude of the coupling parameter  $\kappa$  depends on the layout of the experiment and the QD material.  $\kappa$  can be large; e.g., one can approximate its magnitude by the Coulomb interaction of two electric point charges that

are 250 nm apart, giving  $\kappa \approx \frac{e^2}{4\pi\epsilon_0\epsilon_r}\frac{1}{250~\mathrm{nm}} \approx 500~\mu\mathrm{eV}$  for the dielectric constant  $\epsilon_r = 11.7$  of silicon.<sup>47</sup> This value agrees with the approximation of a few tenth of meV in Ref. [48].

The entangling operations that follow require much smaller  $\kappa$  than the naive estimate given above. The environment around the QDs<sup>49</sup> and the metallic gates partly screen the capacitive couplings between the HQs, and thus they reduce  $\kappa$ . Also the layout of the four QDs can be designed such that the Coulomb interactions between neighboring HQs are lowered.<sup>50</sup> Finally, bringing QD<sub>2</sub><sup>L</sup> and QD<sub>1</sub><sup>R</sup> further apart lowers  $\kappa$ .

For two HQs operated at their sweet spots,  $\epsilon_*^L$  and  $\epsilon_*^R$ , the projection of Eq. (7) to the subspace  $\left\{\left|\overline{1}^L\overline{1}^R\right\rangle,\left|\overline{1}^L\overline{0}^R\right\rangle,\left|\overline{0}^L\overline{1}^R\right\rangle,\left|\overline{0}^L\overline{0}^R\right\rangle\right\}$  gives the two-qubit interaction

$$C_{2Q} = \mathcal{X}_{\mathcal{C}} \sigma_x^{\mathcal{L}} \sigma_x^{\mathcal{R}}, \tag{8}$$

with  $\mathcal{X}_{\mathcal{C}} = -\frac{\kappa}{4}\sin^2\left(\theta_*^{\rm L}/2\right)\sin^2\left(\theta_*^{\rm R}/2\right)$ . Eq. (8) lowers the energies of the configurations  $\left|\overline{1}^{\rm L}\overline{1}^{\rm R}\right\rangle + \left|\overline{0}^{\rm L}\overline{0}^{\rm R}\right\rangle$  and  $\left|\overline{0}^{\rm L}\overline{1}^{\rm R}\right\rangle + \left|\overline{1}^{\rm L}\overline{0}^{\rm R}\right\rangle$  compared to  $\left|\overline{1}^{\rm L}\overline{1}^{\rm R}\right\rangle - \left|\overline{0}^{\rm L}\overline{0}^{\rm R}\right\rangle$  and  $\left|\overline{0}^{\rm L}\overline{1}^{\rm R}\right\rangle - \left|\overline{1}^{\rm L}\overline{0}^{\rm R}\right\rangle$ . The first states have large weights in (2,1,2,1) or (1,2,1,2), while the latter states have large weights in (1,2,2,1) or (2,1,1,2).

Additionally to Eq. (8), there are also the single-qubit interactions

$$C_{1Q} = X_{\mathcal{C}}^{\mathcal{L}} \sigma_x^{\mathcal{L}} + X_{\mathcal{C}}^{\mathcal{R}} \sigma_x^{\mathcal{R}}, \tag{9}$$

with  $X_{\mathcal{C}}^{\rm L} = -\frac{\kappa}{4} \sin^2 \left(\theta_*^{\rm L}/2\right) \sin^2 \left(\theta_*^{\rm R}/2\right)$  and  $X_{\mathcal{C}}^{\rm R} = \frac{\kappa}{4} [1 + \cos^2 \left(\theta_*^{\rm L}/2\right)] \sin^2 \left(\theta_*^{\rm R}/2\right)$ .

#### B. Exchange Coupling

Encoded qubits in the multielectron regime have a large number of spin states that are not part of the computational subspace.<sup>8</sup> As a consequence, the time evolution out of the computational subspace, which is called leakage, must be considered.<sup>5,51</sup> Similar to TQDs, interqubit tunnel couplings between HQs can cause leakage because the subspaces of different local spin quantum numbers are coupled.<sup>6,52</sup> It will be shown that the system of two HQs at their sweet spots have large energy separations between leakage and computational states, which suppresses leakage events (cf. similar approaches for TQDs in Refs. [53,54]).

In the six-electron configuration, only states with total  $s_z=1$  are considered because the spin directions are conserved during tunneling events. Tab. I summarizes the spin states with the lowest energies. The computational subspace  $\left\{\left|\overline{1}^L\overline{1}^R\right\rangle,\left|\overline{1}^L\overline{0}^R\right\rangle,\left|\overline{0}^L\overline{1}^R\right\rangle,\left|\overline{0}^L\overline{0}^R\right\rangle\right\}$  and the leakage states (called  $|\alpha\rangle,|\beta\rangle,|\gamma\rangle,|\delta\rangle$ , and  $|\nu\rangle$ ) are considered. Only the states with S=1/2 are able to couple

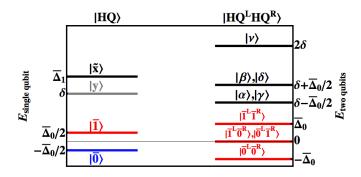


Figure 3. States with the lowest energies for a HQ and for the combined system of two identical HQs in the absence of inter-qubit exchange and Coulomb interactions. Each HQ is operated at  $\epsilon_*=\epsilon_*^{\rm L}=\epsilon_*^{\rm R}$ . The states of a HQ are shown on the left (cf. Fig. 2); the qubit states are labeled by  $\left|\overline{1}\right\rangle$  and  $\left|\overline{0}\right\rangle$ . The leakage states are the excited, hybridized state between the (2,1) and (1,2) configurations  $\left|\widetilde{x}\right\rangle$  and the  $S=3/2,\ s_z=1/2$  triplet state  $\left|y\right\rangle$ . The two-qubit states are shown on the right. The computational subspace  $\left\{\left|\overline{1}^{\rm L}\overline{1}^{\rm R}\right\rangle,\left|\overline{1}^{\rm L}\overline{0}^{\rm R}\right\rangle,\left|\overline{0}^{\rm L}\overline{1}^{\rm R}\right\rangle,\left|\overline{0}^{\rm L}\overline{0}^{\rm R}\right\rangle\right\}$  is well separated in energy from all the leakage states  $\left|\alpha\right\rangle,\left|\beta\right\rangle,\left|\gamma\right\rangle,\left|\delta\right\rangle,$  and  $\left|\nu\right\rangle$  that are defined in Tab. I.

the (2,1) and (1,2) configurations at  $\mathrm{QD}_1^\mathrm{L}$  and  $\mathrm{QD}_2^\mathrm{L}$  or at  $\mathrm{QD}_1^\mathrm{R}$  and  $\mathrm{QD}_2^\mathrm{R}$ . These states have lower energies than the state with S=3/2 of the same  $s_z$  (cf. Fig. 2:  $\left|\overline{1}\right\rangle$  and  $\left|\overline{0}\right\rangle$  have S=1/2,  $\left|y\right\rangle$  has S=3/2). As a consequence, all the computational states have lower energies than the leakage states (unless  $\delta^\mathrm{L}, \delta^\mathrm{R} \lesssim \frac{\overline{\Delta}_0^\mathrm{L}}{2}, \frac{\overline{\Delta}_0^\mathrm{R}}{2}$ ). Fig. 3 shows the energies of the single-qubit states and the leakage states for two identical HQs.

A tunnel coupling between  $QD_2^L$  and  $QD_1^R$  couples the (2,1) and (1,2) configurations at these QDs. Similar to the single-qubit interactions in Sec. II, I phenomenologically introduce a state coupling between  $QD_2^L$  and  $QD_1^R$ :

$$\mathcal{H}' = -t_1 \mid \uparrow S \rangle \left( \sqrt{\frac{2}{3}} \langle T_+ \downarrow \mid -\sqrt{\frac{1}{3}} \langle T_0 \uparrow \mid \right) + t_0 \mid \uparrow S \rangle \langle S \uparrow \mid + \text{h.c.}$$
 (10)

Note that only the states with S = 1/2,  $s_z = 1/2$  at  $QD_2^L$  and  $QD_1^R$  are coupled in Eq. (10). All triplets at  $QD_1^R$  are neglected because these states have much higher energies.

The setup can be tuned towards the (1,1,2,2) configuration. Only states with a singlet at  $\mathrm{QD}_1^{\mathrm{R}}$  are considered, giving the four states  $\{|\uparrow\uparrow \mathrm{S} \; \mathrm{S}\rangle , |\uparrow\uparrow \mathrm{S} \; \mathrm{T}_0\rangle , |\uparrow\downarrow \mathrm{S} \; \mathrm{T}_+\rangle , |\downarrow\uparrow \mathrm{S} \; \mathrm{T}_+\rangle \}$  with  $s_z=1$ . If the (1,1,2,2) spin configuration is only virtually excited, then  $\mathcal{H}'$  can be eliminated using Schrieffer-Wolff perturbation theory. 55–57 Only the effective interactions on the qubit subspace are summarized in the following; Appx. B gives a detailed summary of their derivations.

There is an effective two-qubit interaction

$$\mathcal{E}_{2Q} = \mathcal{X}_{\mathcal{E}} \sigma_x^{\mathcal{L}} \sigma_x^{\mathcal{R}} + \mathcal{Z}_{\mathcal{E}} \sigma_z^{\mathcal{L}} \sigma_x^{\mathcal{R}}, \tag{11}$$

Table I. Relevant two-qubit states with total  $s_z=1$  for two HQs. All the states of a three-electron DQD with  $S=1/2,\ s_z=\pm 1/2$  have contributions in the (2,1) and (1,2) configurations. The computational subspace  $\left\{\left|\overline{1}^L\overline{1}^R\right\rangle,\left|\overline{1}^L\overline{0}^R\right\rangle,\left|\overline{0}^L\overline{0}^R\right\rangle,\left|\overline{0}^L\overline{0}^R\right\rangle\right\}$  is energetically separated from all the leakage states. I use the abbreviations  $|\overline{v}_1\rangle$  and  $|\overline{v}_0\rangle$  for the basis states in  $S=1/2,\ s_z=-1/2$  that are obtained from  $|\overline{1}\rangle$  and  $|\overline{0}\rangle$  by flipping all the spins. The states  $|\alpha\rangle,\left|\beta\rangle,\left|\gamma\rangle,\left|\delta\rangle\right\rangle$ , and  $|\nu\rangle$  label the leakage states with the energies  $\frac{\overline{\Delta}_0^L}{2}+\delta^R,-\frac{\overline{\Delta}_0^L}{2}+\delta^R,\delta^L+\frac{\overline{\Delta}_0^R}{2},\delta^L-\frac{\overline{\Delta}_0^R}{2}$ , and  $\delta^L+\delta^R$ .

$$\begin{vmatrix} \overline{1}^L \overline{1}^R \rangle \\ \overline{1}^L \overline{0}^R \rangle \\ \overline{0}^L \overline{0}^R \rangle \\ \overline{0}^L \overline{0}^R \rangle \\ \overline{0}^L \overline{0}^R \rangle \\ \overline{0}^L \overline{0}^R \rangle \\ \begin{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \overline{0}^L \overline{0}^R \rangle \\ \end{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \begin{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \overline{0}^L \overline{0}^R \rangle \\ \end{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \begin{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \begin{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \end{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \end{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ \begin{vmatrix} \overline{0}^L \overline{0}^R \rangle \\ |\alpha_1\rangle = \left| \overline{1}^L \right\rangle \left[ \sqrt{\frac{1}{3}} |\downarrow T_+\rangle + \sqrt{\frac{2}{3}} |\uparrow T_0\rangle \right] \\ |\alpha_2\rangle = \left| \overline{v}_1^L \right\rangle |\uparrow T_+\rangle \\ \end{vmatrix} \frac{(\frac{1}{2}, \frac{1}{2})}{(\frac{1}{2}, \frac{1}{2})} \frac{(\frac{3}{2}, \frac{1}{2})}{(\frac{3}{2}, \frac{3}{2})} \right\} \overline{0}^L \overline{0}^L \wedge \overline{0}^R \rangle \\ |\beta_1\rangle = \left| \overline{0}^L \right\rangle \left[ \sqrt{\frac{1}{3}} |\downarrow T_+\rangle + \sqrt{\frac{2}{3}} |\uparrow T_0\rangle \right] |\overline{1}^R \rangle \\ |\beta_2\rangle = \left| \overline{v}_0^L \right\rangle |\uparrow T_+\rangle \\ \end{vmatrix} \frac{(\frac{1}{2}, \frac{1}{2})}{(\frac{3}{2}, \frac{3}{2})} \frac{(\frac{3}{2}, \frac{1}{2})}{(\frac{3}{2}, \frac{3}{2})} \right\} \overline{0}^L \wedge \overline{0}^R \rangle \\ |\gamma_1\rangle = \left[ \sqrt{\frac{1}{3}} |\downarrow T_+\rangle + \sqrt{\frac{2}{3}} |\uparrow T_0\rangle \right] |\overline{0}^R \rangle \\ |\gamma_2\rangle = |\uparrow T_+\rangle |\overline{v}_1^R \rangle \\ |\delta_1\rangle = \left[ \sqrt{\frac{1}{3}} |\downarrow T_+\rangle + \sqrt{\frac{2}{3}} |\uparrow T_0\rangle \right] |\overline{0}^R \rangle \\ |\delta_2\rangle = |\uparrow T_+\rangle |\overline{v}_0^R \rangle \\ |\delta_2\rangle = \left[ \sqrt{\frac{1}{3}} |\downarrow T_+\rangle + \sqrt{\frac{2}{3}} |\uparrow T_0\rangle \right] \left[ \sqrt{\frac{1}{3}} |\downarrow T_+\rangle + \sqrt{\frac{2}{3}} |\uparrow T_0\rangle \right] (\frac{3}{2}, \frac{1}{2}) \\ |\nu_2\rangle = \left[ \sqrt{\frac{1}{3}} |\uparrow T_-\rangle + \sqrt{\frac{2}{3}} |\downarrow T_0\rangle \right] |\uparrow T_+\rangle \\ |\nu_3\rangle = |\uparrow T_+\rangle \left[ \sqrt{\frac{1}{3}} |\uparrow T_-\rangle + \sqrt{\frac{2}{3}} |\downarrow T_0\rangle \right] \rangle$$

with  $\mathcal{X}_{\mathcal{E}} = -\left[\frac{1-c_{\mathrm{R}}^2}{4}\right]J_0 + \left[\frac{c_{\mathrm{L}}^2(3-11c_{\mathrm{R}}^2)}{108}\right]J_1$  and  $\mathcal{Z}_{\mathcal{E}} = -\left[\frac{c_{\mathrm{L}}(1-c_{\mathrm{R}}^2)}{6}\right]\sqrt{J_0J_1}$ .  $J_0 = \frac{t_0^2}{E_{(1,1,2,2)}-E_{(1,2,1,2)}}$  and  $J_1 = \frac{t_1^2}{E_{(1,1,2,2)}-E_{(1,2,1,2)}}$  are the effective coupling constants that are determined by the energy difference  $E_{(1,1,2,2)}-E_{(1,2,1,2)}$  between (1,1,2,2) and (1,2,1,2).  $c_{\mathrm{L}}$  [ $c_{\mathrm{R}}$ ] is the abbreviation for  $\cos\left(\theta_{\mathrm{L}}^*/2\right)$  [ $\cos\left(\theta_{\mathrm{R}}^*/2\right)$ ]. Note that there is additionally a single-qubit Hamiltonian

$$\mathcal{E}_{1Q} = Z_{\mathcal{E}}^{\mathcal{L}} \sigma_{z}^{\mathcal{L}} + X_{\mathcal{E}}^{\mathcal{L}} \sigma_{x}^{\mathcal{L}} + X_{\mathcal{E}}^{\mathcal{R}} \sigma_{x}^{\mathcal{R}}, \tag{12}$$

with 
$$Z_{\mathcal{E}}^{\mathcal{L}} = \left[\frac{c_{\mathcal{L}}(1+c_{\mathcal{R}}^2)}{6}\right] \sqrt{J_0 J_1}$$
,  $X_{\mathcal{E}}^{\mathcal{L}} = \left[\frac{1+c_{\mathcal{R}}^2}{4}\right] J_0 - \left[\frac{c_{\mathcal{L}}^2(3+11c_{\mathcal{R}}^2)}{108}\right] J_1$ , and  $X_{\mathcal{E}}^{\mathcal{R}} = \left[\frac{1-c_{\mathcal{R}}^2}{4}\right] J_0 + \left[\frac{c_{\mathcal{L}}^2(3-11c_{\mathcal{R}}^2)}{108}\right] J_1$ .

Besides Eq. (11) and Eq. (12), the effective Hamiltonian also contains contributions for the leakage states and between leakage and computational states. All these contributions will be included in the numerical calculations that contain inter-qubit exchange interactions. Assuming large energy separations between the computational and

leakage states, these interactions introduce minor effects for the qubit's time evolution, and they can be neglected.

### IV. UNIVERSAL QUBIT CONTROL

I discuss gate operations for the parameters (A)  $\overline{\Delta}_0^L \approx \overline{\Delta}_0^R$  and (B)  $\overline{\Delta}_0^L \gg \overline{\Delta}_0^R$ . Note that the HQs are always operated at their sweet spots  $\epsilon_*^L$  and  $\epsilon_*^R$ .

## A. Nearly identical qubits $\overline{\Delta}_0^{\mathbf{L}} \approx \overline{\Delta}_0^{\mathbf{R}}$

I consider the Hamiltonian:

$$\mathcal{H}_{A} = \frac{\overline{\Delta}_{0}^{L} + Z^{L}}{2} \sigma_{z}^{L} + \frac{\overline{\Delta}_{0}^{R}}{2} \sigma_{z}^{R} + \mathcal{X} \sigma_{x}^{L} \sigma_{x}^{R}.$$
 (13)

If  $HQ^L$  and  $HQ^R$  are in resonance,  $Z^L = \overline{\Delta}_0^R - \overline{\Delta}_0^L$ , then  $HQ^L$  and  $HQ^R$  entangle under static time evolutions. In

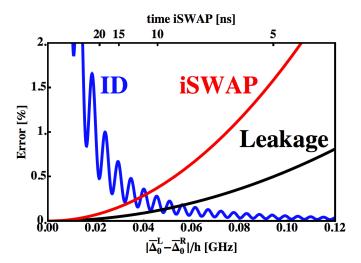


Figure 4. Gate operations for two HQs with similar eigenfrequencies  $\overline{\Delta}_0^L \approx \overline{\Delta}_0^R$  that use the static Coulomb interaction according to Eq. (8), with  $\mathcal{X}_{\mathcal{C}}/h \approx 1.3$  MHz, and the tunable exchange interactions from Eq. (11)-(12). A small detuning  $\overline{\Delta}_0^R - \overline{\Delta}_0^L \gg \mathcal{X}_\mathcal{C}$  is sufficient to neglect the interactions between  $HQ^L$  and  $HQ^R$  such that the qubits evolve independent dently. ID shows the infidelity, according to Eq. (A1), of a static time evolution with the given parameters and  $\mathcal{X} = \mathcal{X}_{\mathcal{C}}$ , which is compared to the ideal time evolution with  $\mathcal{X} = 0$ after the time  $t = h/(4\mathcal{X}_{\mathcal{C}})$ . Adding a small tunnel coupling between QD<sub>2</sub><sup>L</sup> and QD<sub>1</sub><sup>R</sup> and tuning the spin configuration towards (1,1,2,2) brings  $HQ^L$  into resonance with  $HQ^R$ (cf. Eq. (12),  $Z_{\mathcal{E}}^{\mathrm{L}} = \overline{\Delta}_{0}^{\mathrm{R}} - \overline{\Delta}_{0}^{\mathrm{L}}$ ). The HQs entangle after  $t = h/(4\mathcal{X})$  for  $\mathcal{X} = \mathcal{X}_{\mathcal{C}} + \mathcal{X}_{\mathcal{E}}$ . iSWAP shows the infidelity, according to Eq. (A1), of the entangling operation with the given parameters, which is compared to an ideal entangling operation according to Eq. (13). The qubits can be operated independently for  $\left|\overline{\Delta}_{0}^{\mathrm{R}}-\overline{\Delta}_{0}^{\mathrm{L}}\right|/h>20$  MHz. When the inter-qubit exchange interaction increases,  $\mathrm{HQ^L}$  and  $\mathrm{HQ^R}$  are brought into resonance to construct high-fidelity entangling operations. Note that also leakage errors increase with the inter-qubit exchange interactions, as discussed in the text.

this case, the two-qubit interaction is

$$\mathcal{H}_{A}^{rwa} = \frac{\mathcal{X}}{2} \left( \sigma_{x}^{L} \sigma_{x}^{R} + \sigma_{y}^{L} \sigma_{y}^{R} \right)$$
 (14)

in the rotating frame with  $\frac{\overline{\Delta}_0^{\rm R}}{2} \left( \sigma_z^{\rm L} + \sigma_z^{\rm R} \right)$  for  $\overline{\Delta}_0^{\rm R} \gg \mathcal{X}$ . After the time  $t = \frac{h}{4\mathcal{X}}$ , the iSWAP gate is created, which is maximally entangling.<sup>58,59</sup> On the other hand, the two-qubit interaction in Eq. (13) can be neglected for  $\overline{\Delta}_0^{\rm L} + Z^{\rm L} \neq \overline{\Delta}_0^{\rm R} \gg \mathcal{X}$  and all single-qubit gates can be realized with the methods that were described in Sec. II.

Altogether, universal qubit control requires rapid control over  $Z^{\rm L}$ . For  $Z^{\rm L}=0$ , all the single-qubit gates can be realized with resonant drivings of the qubits at their eigenfrequencies. For  $Z^{\rm L}=\overline{\Delta}_0^{\rm R}-\overline{\Delta}_0^{\rm L}$ , the HQs entangle under static time evolutions.

In the configurations of Fig. 1,  $\mathcal{X}$  in Eq. (13) has contributions from the capacitive couplings between the charge

configurations  $\mathcal{X}_{\mathcal{C}}$  (cf. Sec. III A) and from the exchange interaction  $\mathcal{X}_{\mathcal{E}}$  between  $\mathrm{QD}_2^{\mathrm{L}}$  and  $\mathrm{QD}_1^{\mathrm{R}}$  (cf. Sec. III B):  $\mathcal{X} = \mathcal{X}_{\mathcal{C}} + \mathcal{X}_{\mathcal{E}}$ . The exchange interaction causes also a frequency shift of  $\mathrm{HQ}^{\mathrm{L}}$  [ $Z_{\mathcal{E}}^{\mathrm{L}}$  in Eq. (12)] which can be controlled electrically. Note that the Coulomb interaction remains constant during the qubit manipulations because the HQs are always operated at their sweet spots. The single-qubit interactions from Eq. (9) are neglected because they only modify the positions of the anticrossings  $\epsilon_{\mathbf{k}}^{\mathrm{L}}$  and  $\epsilon_{\mathbf{k}}^{\mathrm{R}}$ .

 $\overline{\Delta}_0^{\rm L}$  and  $\overline{\Delta}_0^{\rm R}$  should have similar magnitudes such that only small inter-qubit exchange interactions are needed to bring HQ<sup>L</sup> and HQ<sup>R</sup> into resonance. Still,  $\overline{\Delta}_0^{\rm L}$  and  $\overline{\Delta}_0^{\rm R}$  are sufficiently distinct for independent single-qubit control. The capacitive coupling  $\mathcal{X}_C$  between the HQs must remain much smaller than in the naive approximations in Sec. III A. Fig. 4 shows simulations with  $\kappa = 0.04~\mu {\rm eV}$  and all the parameters defined earlier. For the Coulomb interactions, only the two-qubit interaction  $\mathcal{X}_C$  is taken into account according to Eq. (8). The exchange interaction contains all the contributions from Eq. (11) and Eq. (12).

If the exchange interactions between HQ<sup>L</sup> and HQ<sup>R</sup> [ $Z_{\mathcal{E}}^{L}$  in Eq. (12) and  $Z^{L}$  in Eq. (13)] cancel the detuning between the HQs, then the entangling gate is realized. Simultaneously with the single-qubit energy shift, also  $X_{\mathcal{E}}^{L}$  and  $X_{\mathcal{E}}^{R}$  from Eq. (12) increase. These interactions cause systematic gate errors. Fig. 4 shows that the gate errors of the iSWAP below 1% can be realized for  $\left|\overline{\Delta}_{0}^{R}-\overline{\Delta}_{0}^{L}\right|/h<80$  MHz. Leakage errors are also caused by the exchange couplings between HQ<sup>L</sup> and HQ<sup>R</sup>, and these leakage events significantly contribute to the gate infidelities. Fig. 5 extracts the leakage errors during an entangling gate with finite tunnel couplings between HQ<sup>L</sup> and HQ<sup>R</sup>. The leakage probability is extracted from the time evolution  $\mathcal{U}$  by taking the norm of the matrix  $\left|\mathcal{U}_{\mathcal{P}_{\mathcal{C}}\mathcal{P}_{\mathcal{L}}}\right|^{2}$  between the states from the computational subspace  $\mathcal{P}_{\mathcal{C}}$  and the leakage subspace  $\mathcal{P}_{\mathcal{L}}$ .

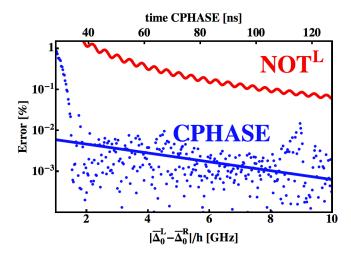
If  $Z^{L}$  is reduced, then  $HQ^{L}$  and  $HQ^{R}$  decouple. Fig. 4 compares the time evolution of Eq. (13) with the time evolution of

$$\mathcal{H}_{A}^{\text{ideal}} = \frac{\overline{\Delta}_{0}^{L}}{2} \sigma_{z}^{L} + \frac{\overline{\Delta}_{0}^{R}}{2} \sigma_{z}^{R}.$$
 (15)

The differences rise significantly if  $\left|\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}\right|$  decreases; but the infidelities stay below 1% for  $\left|\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}\right|/h > 20~{\rm MHz}$ .

### B. Distinct qubits $\overline{\Delta}_0^L \gg \overline{\Delta}_0^R$

Highly detuned HQs (e.g.  $\overline{\Delta}_0^{\rm L} \gg \overline{\Delta}_0^{\rm R}$ ) can be operated exclusively with microwave signals. The  $\sigma_x^{\rm L} \sigma_x^{\rm R}$  interaction between HQ<sup>L</sup> and HQ<sup>R</sup> can be neglected without drivings, and if both qubits are driven with their own



Resonant manipulations of two HQs with large detunings between their eigenfrequencies  $\overline{\Delta}_0^{\rm L}/h$  and  $\overline{\Delta}_0^{\rm R}/h$  of a few GHz. The qubits interact via the Coulomb interaction, according to Eq. (8), with  $\mathcal{X}_{\mathcal{C}}/h = 0.13$  GHz. A resonant drive of HQ<sup>L</sup> at its eigenfrequency realizes a state inversion of HQ<sup>L</sup>, while HQ<sup>R</sup> evolves trivially. The NOT<sup>L</sup> gate is realized after the time t = h/(4A) for a drive  $A \cos \left(\overline{\Delta}_0^{L} t/h\right)$ with A/h = 0.1 GHz. The time evolution is compered to an ideal NOT<sup>L</sup> with  $\mathcal{X}_{\mathcal{C}} = 0$ , showing that the gate infidelity, according to Eq. (A1), is lower than 1%. A similar drive of  $HQ^L$  with the frequency  $\overline{\Delta}_0^R/h$  entangles  $HQ^L$  and  $HQ^R$ . The resulting gate operation is equivalent to a CPHASE gate up to single-qubit gates. In the simulations, the gate times of the entangling gates are optimized numerically to cancel high-frequency fluctuations. The gate errors are quantified by the deviations of the Makhlin invariants from their ideal values  $(|G_1| + |G_2 - 1|)$ .<sup>60</sup>  $\left| \overline{\Delta}_0^{\text{L}} - \overline{\Delta}_0^{\text{R}} \right| / h > 2$  GHz permits high-fidelity CPHASE gates.

resonance frequencies. In the cross-resonance protocol, one qubit is driven at the eigenfrequency of the other qubit,  $^{61-64}$  e.g.,

$$\mathcal{H}_{\rm B} = \frac{\overline{\Delta}_0^{\rm L}}{2} \sigma_z^{\rm L} + \mathcal{A} \cos \left( 2\pi \frac{\overline{\Delta}_0^{\rm R}}{h} t \right) \sigma_x^{\rm L} + \frac{\overline{\Delta}_0^{\rm R}}{2} \sigma_z^{\rm R} + \mathcal{X} \sigma_x^{\rm L} \sigma_x^{\rm R}.$$
(16)

Transforming Eq. (16) to the rotating frame with  $\frac{\overline{\Delta}_0^{\rm R}}{2} \left( \sigma_z^{\rm L} + \sigma_z^{\rm R} \right)$  gives after a rotating wave approximation

$$\mathcal{H}_{\mathrm{B}}^{\mathrm{rwa}} = \frac{\overline{\Delta}_{0}^{\mathrm{L}} - \overline{\Delta}_{0}^{\mathrm{R}}}{2} \sigma_{z}^{\mathrm{L}} + \frac{\mathcal{A}}{2} \sigma_{x}^{\mathrm{L}} + \frac{\mathcal{X}}{2} \left( \sigma_{x}^{\mathrm{L}} \sigma_{x}^{\mathrm{R}} + \sigma_{y}^{\mathrm{L}} \sigma_{y}^{\mathrm{R}} \right). \tag{17}$$

Another rotating wave approximation gives the effective interaction

$$\mathcal{H}_{\mathrm{B}}^{\mathrm{rwa}_{2}} = \frac{\mathcal{X}}{2} \frac{\mathcal{A}}{\sqrt{\left(\overline{\Delta}_{0}^{\mathrm{L}} - \overline{\Delta}_{0}^{\mathrm{R}}\right)^{2} + \mathcal{A}^{2}}} \times \left[\cos\left(\vartheta\right)\sigma_{z}^{\mathrm{L}} + \sin\left(\vartheta\right)\sigma_{x}^{\mathrm{L}}\right]\sigma_{x}^{\mathrm{R}}$$

$$(18)$$

in the rotating frame with  $\frac{\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}}{2} \sigma_z^{\rm L} + \frac{\mathcal{A}}{2} \sigma_x^{\rm L}$ . I use the abbreviations  $\cos{(\vartheta)} = \frac{\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}}{\sqrt{\left(\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}\right)^2 + \mathcal{A}^2}}$  and  $\sin{(\vartheta)} = \frac{1}{2} \left(\frac{\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}}{2}\right)^2 + \mathcal{A}^2}$ 

$$\frac{\mathcal{A}}{\sqrt{\left(\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}\right)^2 + \mathcal{A}^2}} \text{ in Eq. (18). A drive for the time } t = \frac{\mathcal{X}}{16} \frac{\mathcal{A}}{\sqrt{\left(\overline{\Delta}_0^{\rm L} - \overline{\Delta}_0^{\rm R}\right)^2 + \mathcal{A}^2}} \text{ entangles the HQs because the time}$$

evolution of Eq. (18) is equivalent to a CPHASE gate.<sup>65</sup> This entangling operation only requires the  $\sigma_x^L \sigma_x^R$  interaction, which can be obtained from the Coulomb interaction between the HQs [see Eq. (8)]. The numerical simulations use  $\kappa = 4 \mu \text{eV}$ , which is smaller than the suggested value from the naive estimates in Sec. III A. Because the inter-qubit exchange interactions are not needed, which would require QDs in close vicinity, one can reduce  $\kappa$  in Eq. (7) by sufficiently separating the DQDs. In this case, there are no leakage errors (see Sec. III B) because the electron transfer between the QDs is forbidden. I simulate the time evolutions according to Eq. (16) without any rotating wave approximations. Besides the dominant time evolution from Eq. (18), there are rapidly oscillating terms that were neglected in the rotating wave approximations in Eq. (17) and Eq. (18).

Fig. 5 shows the errors of entangling operations for  $\mathcal{X}=0.55~\mu\text{eV}$ , driving amplitudes  $\mathcal{A}/h=0.1~\text{GHz}$ , and the HQ parameters defined earlier. To realize high-fidelity CPHASE operations, the deviations of the Makhlin invariants from  $G_1=0$  and  $G_2=1$  are minimized. This routine cancels artifacts that are neglected in the rotating wave approximations of Eq. (16) and Eq. (17). If the HQs are detuned by several GHz, then high-fidelity entangling operations can be realized. Fig. 5 also shows that high-fidelity single-qubit operations can be realized in the same setup if the HQs' eigenfrequencies are detuned by a few GHz.

### V. NOISE DISCUSSION

This section shows that noise from fluctuating magnetic and electric fields only causes small errors for HQs. In the following, a HQ is analyzed in the eigenbasis  $\left\{\left|\overline{1}\right\rangle,\left|\overline{0}\right\rangle\right\}$  according to Eq. (3) because it is operated at its sweet spot  $\epsilon_*$ .

### A. Hyperfine Interactions

Fluctuating local magnetic fields were identified as a natural problem for spin qubits. <sup>66</sup> The nuclear magnetic fields of the host's nuclei couples via the contact hyperfine interaction to the spin of an electron. <sup>67–69</sup> For localized electrons, the contact hyperfine interaction can be described by slowly-fluctuating local magnetic fields at the QDs:  $\delta B^{\rm QD_1}$  and  $\delta B^{\rm QD_2}$ .

QDs:  $\delta \boldsymbol{B}^{\mathrm{QD}_1}$  and  $\delta \boldsymbol{B}^{\mathrm{QD}_2}$ . For the HQ, a noise term  $\mathcal{H}^{\delta \boldsymbol{B}} = \frac{g\mu_B}{2} (\delta \boldsymbol{B}^{\mathrm{QD}_1} \cdot \boldsymbol{\sigma}^{\mathrm{QD}_1} + \delta \boldsymbol{B}^{\mathrm{QD}_2} \cdot \boldsymbol{\sigma}^{\mathrm{QD}_2})$  describes the fluctuating magnetic fields, where  $\boldsymbol{\sigma}^{\mathrm{QD}_i} = (\sigma_x^{\mathrm{QD}_i}, \sigma_y^{\mathrm{QD}_i}, \sigma_z^{\mathrm{QD}_i})$  are the Pauli operators for the electrons at  $\mathrm{QD}_i$ . For the HQ, this term gives the contribution

$$\mathcal{H}_{\{|\bar{1}\rangle,|\bar{0}\rangle\}}^{\delta B} = \delta_B \sigma_x, \tag{19}$$

$$\begin{array}{ll} \text{with} \;\; \delta_{B} \;\; = \;\; \frac{g\mu_{B}}{2} \left[ -\frac{3+\cos^{2}\left(\frac{\theta}{2}\right)}{6} \delta B_{z}^{\mathrm{QD}_{1}} + \frac{8\cos^{2}\left(\frac{\theta}{2}\right)}{6} \delta B_{z}^{\mathrm{QD}_{2}} \right] \\ \text{and} \;\; \sigma_{x} = \; \left| \overline{1} \right\rangle \left\langle \overline{0} \right| \, + \; \left| \overline{0} \right\rangle \left\langle \overline{1} \right|. \end{array}$$

The nuclear magnetic field can be treated as static during a single gate operation, but it fluctuates between successive measurements. Typical magnitudes of  $\delta B_z^{\rm QD}$  are 5 mT for GaAs QDs and 100  $\mu$ T for Si QDs. The associate frequencies are  $g\mu_B\delta B_z^{\rm QD}/h\approx 30$  MHz for GaAs QDs and  $g\mu_B\delta B_z^{\rm QD}/h\approx 3$  MHz for Si QDs, while  $\overline{\Delta}_0/h$  reaches several GHz. Therefore, one can treat Eq. (19) as a small perturbation to Eq. (3).

### B. Charge Noise

Fluctuating electric fields are caused by the filling and unfilling of charge traps<sup>39,68</sup> or by fluctuating gate potentials. One can describe the dominant contribution for a DQD qubit by introducing an uncertainty in the detuning parameter  $\epsilon$ ,<sup>40</sup> which causes the noise term

$$\mathcal{H}_{\{|\overline{1}\rangle,|\overline{0}\rangle\}}^{\delta\epsilon} = \frac{\delta^2}{2(\delta^2 + \Delta_1^2)} \delta\epsilon \ \sigma_x \tag{20}$$

for the HQ at the sweet spot  $\epsilon^*$ , with  $\sigma_x = |\overline{1}\rangle\langle\overline{0}| + |\overline{0}\rangle\langle\overline{1}|$ .

Charge fluctuation are slow compared to the gate times. The rms values of  $\delta\epsilon$  reach a few  $\mu\text{eV}$  (1  $\mu\text{eV}/h\approx 0.24~\text{GHz}$ ) in GaAs<sup>22,40,70</sup> and Si.<sup>18</sup> The factor  $\frac{\delta^2}{2(\delta^2+\Delta_1^2)}$  in Eq. (20) gives an algebraic suppression to charge noise compared to a charge qubit. Note that this suppression is much smaller than for spin qubits. <sup>68</sup> The parameters of the previous analysis suggest magnitudes of the fluctuations  $\frac{\delta^2}{2(\delta^2+\Delta_1^2)}$ 1  $\mu\text{eV}/h\approx 76~\text{MHz}$ . This number it still by two orders of magnitudes smaller than  $\overline{\Delta}_0/h\approx 4.5~\text{GHz}$ .

### VI. SUMMARY AND CONCLUSION

This article has analyzed quantum computation for the HQ. The HQ is an exchange-only qubit, where three electrons are confined at a DQD. There are two avoided level crossings between states in (2,1) and (1,2) in the transition region of these charge configurations. Controlled transfers through the avoided crossing have realized single-qubit gates experimentally, 19-21 while the possibility of resonant gates motivates the search for optimal operation points. 21,29,30,43 I introduce such an optimal operation point at a sweet spot that is exceptionally noise insensitive. All the gate operations can be done close to this sweet spot.

This paper has derived an effective qubit description at the sweet spot. Two HQs can be coupled via Coulomb and exchange interactions. If both HQs are operated at their sweet spots, then the Coulomb interaction stays constant but the inter-qubit exchange interaction can be manipulated quickly. In a first approach, two qubits of similar eigenfrequencies are analyzed. The exchange interaction can bring the qubits in and out of resonance. Two qubits of identical eigenfrequencies entangle under static time evolutions, but two distinct qubits evolve independently. In a second approach, two highly distinct qubits are analyzed. The Coulomb interaction stays constant, and only resonant electric signals are needed to realize single-qubit and two-qubit gates.

This paper has simulated HQs in Si and GaAs with realistic parameters that are extracted from experiments. <sup>19–21</sup> Most critically, the gate operations require Coulomb interactions between HQs that are small compared to the naive estimates for the setup. Especially, if inter-qubit exchange interactions are used for the entangling operations, then the inter-qubit Coulomb couplings should be small. This paper has discussed how weak inter-qubit Coulomb couplings can be realized. It should be possible to realize such weak inter-qubit couplings with a careful design of the QD layout.

Fault-tolerant quantum computation requires high-fidelity quantum gates with error probabilities below  $1\%.^{71,72}$  My simulations showed that quantum computation with this infidelities is possible if multi-qubit arrangements of HQ with the described parameters can be fabricated. Nuclear spin noise and charge noise are less critical. Additionally, these statistical errors can be reduced with refocusing protocols with similar approaches as for DQDs<sup>73–75</sup> and TQDs.<sup>30,70</sup> A reduction of the nuclear spin fluctuation can be realized by preparing the nuclear spin bath<sup>76,77</sup> or with QD materials that contain nuclei of zero spins<sup>14,78</sup> if the need arises.

A recent experiment also realized resonant single-qubit gates for the HQ.<sup>79</sup> In this case, the HQ is operated deep in (1,2) which reduces the influence of charge noise. Resonant single-qubit gates are possible when the transition region to (2,1) is approached, while one still stays away from the anticrossings. Two-qubit gates with exchange interactions cannot be used to entangle HQs in Ref. [79] in the same way as in the study of this paper because many leakage states are degenerate with the computational states. In Ref. [79], the S = 3/2,  $s_z = 1/2$  state is nearly degenerate with the qubit states (cf. Fig. 3). The Coulomb interaction can still be used to entangle HQs, similar to Sec. III A, while the interaction Hamiltonian is  $\propto \sigma_z^{\rm L} \sigma_z^{\rm R}$ . Universal qubit control likely requires DC control of the interaction Hamiltonian. Either two HQs are isolated from each other, or they are coupled via  $\sigma_z^L \sigma_z^R$ (in contrast to the approach in Sec. IVB where singlequbit and two-qubit gates are possible without changing the operation points of the HQs).

Overall, the HQ is an interesting candidate for further experimental and theoretical studies. It has many

characteristics of a charge qubit, especially with its fast operation times. On the other hand, it can be protected from charge noise similar to a spin qubit. The described sweet spot manipulations classify the HQ as a mixture of a charge qubit and a spin qubit that has advantages from both setups. This paper has shown that universal gate operations can be realized for the HQ at the threshold of quantum error correction, which should further motivate the search for optimal manipulation protocols of HQs.

### ACKNOWLEDGMENTS

I am grateful for support from the Alexander von Humboldt foundation.

### Appendix A: Gate Fidelities

The fidelity that is used in the paper should be defined in the following. To characterize gate fidelities, the time evolution U is compared to the ideal time evolution  $U_{\mathcal{I}}$ . The state space is doubled to two identical Hilbert spaces R and S. The entanglement fidelity<sup>80</sup>

$$F = \operatorname{tr} \left\{ \rho^{\mathrm{RS}} \mathbf{1}^{\mathrm{R}} \otimes \left[ U_{\mathcal{I}}^{-1} U \right]^{\mathrm{S}} \rho^{\mathrm{RS}} \mathbf{1}^{\mathrm{R}} \otimes \left[ U^{-1} U_{\mathcal{I}} \right]^{\mathrm{S}} \right\}$$
(A1)

is a measure for the gate performance. Eq. (A1) compares the time evolution  $\left[U_{\mathcal{I}}^{-1}U\right]^{\mathrm{S}}$  of S with a reference system R that is unchanged.  $\rho^{\mathrm{RS}} = |\psi\rangle \langle \psi|$  is a maximally entangled state of the combined Hilbert space, e.g.,  $|\psi\rangle = (|0000\rangle + |0110\rangle + |1001\rangle + |1111\rangle)/2$ .

This section describes the derivation of the effective interactions from Sec. IIIB for weak tunnel couplings between HQ<sup>L</sup> and HQ<sup>R</sup>. The HQs are operated at their sweet spots. The dominant Hamiltonian  $\mathcal{H}$  is determined by Eq. (1) [with the approximations in Eq. (3)]. Eq. (10) defines the coupling between QD<sup>L</sup><sub>2</sub> and QD<sup>R</sup><sub>1</sub> (called  $\mathcal{H}'$ ). The system is tuned towards (1,1,2,2), while the computational states still remain in the ground states configurations. The low-energy subspace  $\mathcal{P} = \mathcal{P}_{\mathcal{Q}} + \mathcal{P}_{\mathcal{L}}$  contains the qubit states  $\mathcal{P}_{\mathcal{Q}} = \left\{ \left| \vec{1}^L \vec{1}^R \right\rangle, \left| \vec{1}^L \vec{0}^R \right\rangle, \left| \vec{0}^L \vec{1}^R \right\rangle, \left| \vec{0}^L \vec{0}^R \right\rangle \right\}$ . The leakage subspace contains the states  $\mathcal{P}_{\mathcal{L}} = \left\{ \left| \alpha \right\rangle, \left| \beta \right\rangle, \left| \gamma \right\rangle, \left| \delta \right\rangle, \left| \nu \right\rangle \right\}$  that are defined in Tab. I.

states that have  $QD_1^R$ are included in (1,1,2,2): 0  $\{|\uparrow\uparrow S S\rangle, |\uparrow\uparrow S T_0\rangle, |\uparrow\downarrow S T_+\rangle, |\downarrow\uparrow S T_+\rangle\}.$  A weak tuning towards (1,1,2,2) only occupies Q virtually. Eq. (10) couples states in (1,2,1,2) and (1,1,2,2). Schrieffer-Wolff perturbation theory constructs an effective Hamiltonian on  $\mathcal{P}$ , assuming that the coupling between  $\mathcal{P}$  and  $\mathcal{Q}$  is weak. Additionally,  $\mathcal{Q}$  has higher energy than  $\mathcal{P}^{.55-57}$ 

The effective interaction on  $\mathcal{P}$  is defined in second-order Schrieffer-Wolff perturbation theory by

$$\mathcal{H}_{\mathcal{P}}^{ij} = \mathcal{H}_{\mathcal{P}}^{ij}$$

$$+ \frac{1}{2} \sum_{k \in \mathcal{Q}} \left( \mathcal{H}_{\mathcal{P}\mathcal{Q}}' \right)^{ik} \left( \frac{1}{E_i - E_k} + \frac{1}{E_j - E_k} \right) \left( \mathcal{H}_{\mathcal{Q}\mathcal{P}}' \right)^{ik}.$$
(B1)

Eq. (B1) uses the transition matrix element between the states  $|i\rangle$  and  $|j\rangle$  from  $\mathcal{P}$ :  $\mathcal{H}^{ij}_{\mathcal{P}} = \langle i | \mathcal{H} | j \rangle$ .  $(\mathcal{H}'_{\mathcal{PQ}})^{ik}$  and  $(\mathcal{H}'_{\mathcal{QP}})^{ki}$  are the transition matrix elements between the states  $|i\rangle$  from  $\mathcal{P}$  and  $|k\rangle$  from  $\mathcal{Q}$ .  $E_i$  is the energy of the state  $|i\rangle$ .

In the whole paper, it is assumed that the energy difference between  $\mathcal{P}$  and  $\mathcal{Q}$  is large, especially much larger than the energy differences between states in  $\mathcal{P}$  or between states in  $\mathcal{Q}$ . One can therefore use for all  $|i\rangle \in \mathcal{P}$  and  $|k\rangle \in \mathcal{Q}$ :  $E_i - E_k \approx E_{(1,2,1,2)} - E_{(1,1,2,2)}$ .

Appendix B: Effective Inter-Qubit Exchange Hamiltonian

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$$\begin{split} e^{-i\frac{\pi}{4}\sigma_z^{\mathrm{R}}} e^{-i\frac{\pi}{4}\sigma_x^{\mathrm{R}}} \mathrm{iSWAP} e^{i\frac{\pi}{4}\sigma_z^{\mathrm{L}}} \mathrm{iSWAP} e^{-i\frac{\pi}{4}\sigma_z^{\mathrm{L}}} e^{-i\frac{\pi}{4}\sigma_x^{\mathrm{R}}} \\ &= e^{-i\frac{3\pi}{4}} \mathrm{CPHASE}. \end{split}$$

such that two iSWAPs construct one CPHASE.

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$$e^{-i\frac{\pi}{4}\sigma_z^{\rm L}\sigma_z^{\rm R}}=e^{i\frac{\pi}{4}}e^{-i\frac{5\pi}{4}\sigma_z^{\rm L}}e^{-i\frac{5\pi}{4}\sigma_z^{\rm R}}{\rm CPHASE}.$$

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